TOSHIBA Photocoupler Photorelay

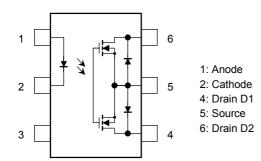
TLP592A

Telecommunications
Measurement and Control Equipment
Data Acquisition System
Measurement Equipment

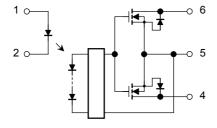
The Toshiba TLP592A consists of a gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a 6-pin DIP package. This photorelay has higher output current rating than phototransistor-type photocoupler; hence, it is suitable for use as On/Off control for high current.

- Normally open (1-form-A) device
- Peak off-state voltage: 60 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 500 mA (max)
- On-state resistance: 2Ω (max)
- Isolation voltage: 2500 Vrms (min)
- UL recognized: UL1557, File No.E67349

Pin Configuration (top view)



Schematic



Weight: 0.4 g (typ.)

最大定格 (Ta = 25°C)

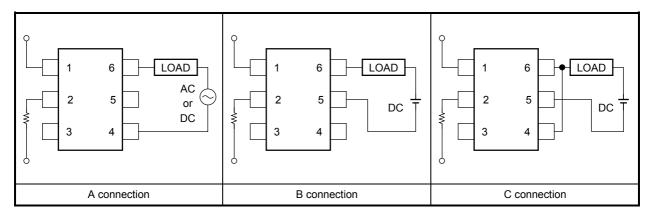
Characteristics			Symbol	Rating	Unit
	Forward curr	ent	lF	50	mA
	Forward curr (Ta ≧ 25°C)	ent derating	ΔI _F /°C	-0.5	mA/°C
LED	Peak forward (100 μs puls		I _{FP}	1	Α
	Reverse volt	age	V _R	5	V
	Junction tem	perature	Tj	125	°C
	Off-state out voltage	put terminal	V _{OFF}	60	V
	On-state current	A connection		500	
		B connection	I _{ON}	500	mA
Detector		C connection		1000	
	Forward current derating (Ta ≥ 25°C)	A connection		-5.0	
		B connection	∆I _{ON} /°C	-5.0	mA/°C
		C connection		-10.0	
	Junction tem	perature	Tj	125	°C
Storage temperature		T _{stg}	-55 to 125	°C	
Operating temperature			T _{opr}	-40 to 85	°C
Lead soldering temperature (10 s)			T _{sol}	260	°C
Isolation voltage (AC, 1 min, R.H. \leq 60%) (Note 1)			BV _S	2500	Vrms

Note 1: LED pins are shorted together. Detector pins are also shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V_{DD}	_	_	48	V
Forward current	IF	5	7.5	25	mA
On-state current	I _{ON}	_	_	500	mA
Operating temperature	T _{opr}	-20	_	65	°C

Circuit Connections



2

Electrical Characteristics Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse voltage	I _R	V _R = 5 V			10	μΑ
	Capacitance	C _T	V = 0, f = 1 MHz	_	30		pF
Detector	Off-state current	I _{OFF}	V _{OFF} = 60 V	_	_	1	μΑ
Detector	Capacitance	C _{OFF}	V = 0, f = 1 MHz	_	130	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current		I _{FT}	I _{ON} = 500 mA	_	1.6	3	mA
Return LED current		I _{FC}	I _{OFF} = 100 μA	0.1	_	_	mA
	A connection	1	$I_{ON} = 500 \text{ mA}, I_{F} = 5 \text{ mA}$	_	1	2	
On-state resistance	B connection		I _{ON} = 500 mA, I _F = 5 mA	_	0.5	1	Ω
	C connection		I _{ON} = 1000 mA, I _F = 5 mA		0.25	_	

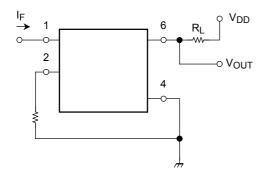
Isolation Characteristics (Ta = 25°C)

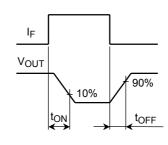
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	V _S = 0 V, f = 1 MHz	_	8.0	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≦ 60%	5×10^{10}	10 ¹⁴	_	Ω
	BV _S	AC, 1 min	2500	_	_	Vrms
Isolation voltage		AC, 1 s, in oil	_	5000	_	VIIIIS
		DC, 1 min, in oil	_	5000	_	Vdc

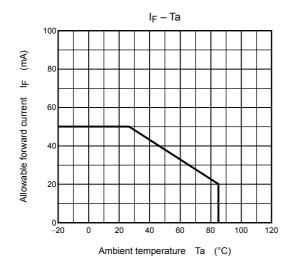
Switching Characteristics (Ta = 25°C)

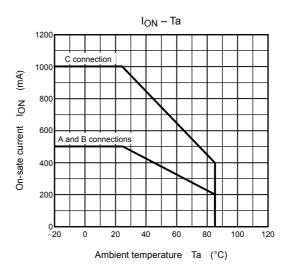
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t _{ON}	$R_L = 200 \Omega$ (Note 2)	_	0.8	2	ms
Turn-off time	toff	$V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$		0.1	0.5	1115

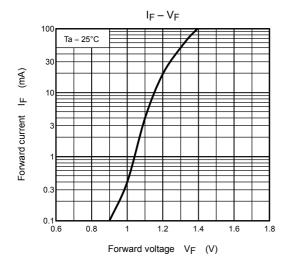
Note 2: Switching time test circuit

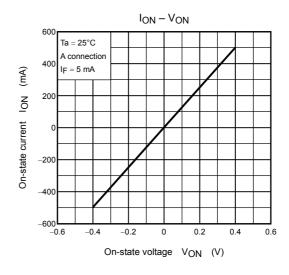


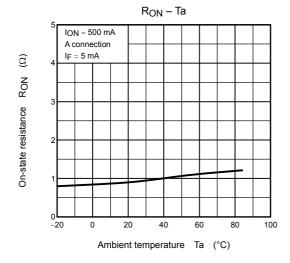


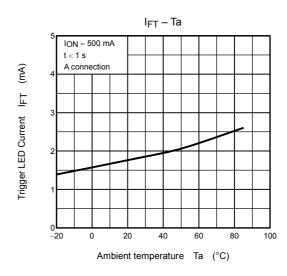


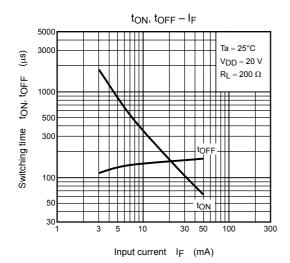


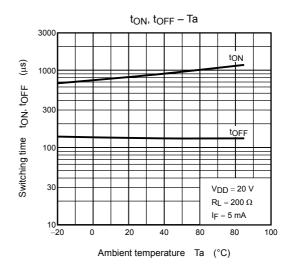


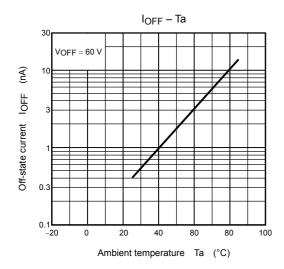












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